JUL-03-2005 07:52 FROM: JASON Z LIN

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REMARKS

In the Office Action, claim 1 is objected to because the limitation "a p-type

quantum-dot epitaxial layer made of an InAlN compound" is not supported by the

specification.

In response, paragraph [0013] is now amended to specifically describe that the p-

type quantum-dot epitaxial layer is made of an InAIN compound as shown in the

above amendment.

Claim 1 is also amended to correct an informality.

Claims 2-6 are cancelled as a result of the Election/Restriction requirement of

office action on 3/8/2005.

The above amendment has been made without prejudice. Claim 1 is now in full

condition for allowance. The specification has also been amended to correct a few

editorial and grammatical errors. Applicant respectfully requests that a timely Notice of

Allowance be issued for this application.

Respectfully submitted,

asoa Z. Lin

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